

1N4448W

Technical Data Data Sheet N0578, Rev. - **Green Products**

1N4448W SURFACE MOUNT FAST SWITCHING DIODE

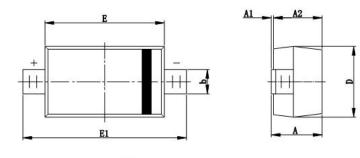
Features:

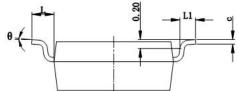
- High Conductance
- Fast Switching
- Surface Mount Package Ideally Suited for Automatic Insertion
- For General Purpose and Switching Application
- Plastic Material –UL Recognition Flammability Classification 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Data:

- Case: SOD-123, Molded Plastic
- Terminals: Plated leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.01 grams(approx.)
- Marking: T5

Mechanical Dimensions: In mm / Inches





Or make al	Dimensions In Millimeters		Dimensions In Inches	
Symbol	Min	Max	Min	Max
А	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.450	0.650	0.018	0.026
С	0.080	0.150	0.003	0.006
D	1.500	1.700	0.059	0.067
E	2.600	2.800	0.102	0.110
E1	3.550	3.850	0.140	0.152
L	0.500 REF		0.020	REF
L1	0.250	0.450	0.010	0.018
θ	0°	8°	0°	8°

SOD-123(CJ)

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com -



Technical Data Data Sheet N0578, Rev. -

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Ordering Information:

Device	Package	Shipping	
1N4448W	SOD-123(Pb-Free)	3000pcs / reel	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings @TA=25°C unless otherwise specified

Characteristic	Symbol	1N4448W	Unit
Non-Repetitive Peak Reverse Voltage	V _{RM}	100	V
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	75	V
RSM Reverse Voltage	V _{R(RMS)}	53	V
Forward Continuous Current(Note 1)	lF	500	mA
Average Rectified Output Current(Note 1)	lo	250	mA
Peak Forward Surge Current @t=1.0us @t=1.0s	I _{FSM}	4.0 2.0	А
Power Dissipation(Note 1)	Pd	500	mW
Typical Thermal Resistance, Junction to Ambient Air(Note 1)	R _{0JA}	357	K/W
Operating and Storage Temperature Range	TJ, TSTG	-65 to +150	°C

Electrical Characteristics @T_A=25°C unless otherwise specified

Characteristic		Symbol	1N4448W	Unit
Forward Voltage	@I _F = 5mA @I _F =10mA	V _{FM}	0.72 1.0	V
Reverse Leakage Current	@V _R =20V @V _R =75V	I _{RM}	25 5.0	nA uA
Junction Capacitance (V _R =0V, f=1.0MHz)		Cj	4.0	pF
Reverse Recovery Time(Note 2)		t _{rr}	4.0	ns

Note: 1. Valid provided that terminals are kept at ambient temperature.

2. Measured with I_F=I_R=10mA, I_{RR}=0.1\times I_R, R_L=100\Omega

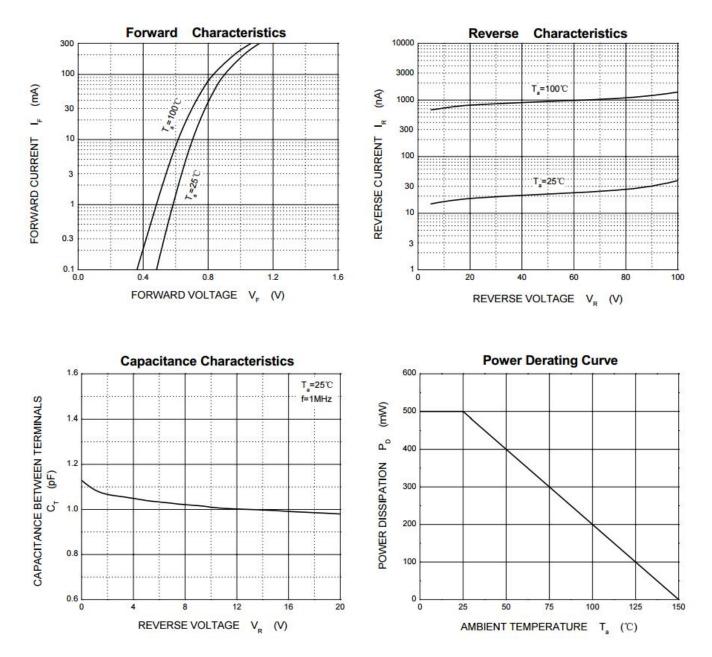
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Typical Characteristics





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